

3BI
2015

1. (a)

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Effective Aperture, A_e : Received power into matched load
Gain = $\frac{\text{max power density in transmitted wave}}{\text{power density from an isotropic source}}$

Radiation, P_r : total power radiated given by $P_r = I^2 R_r$
Resistance

Radiation efficiency η_{rad} : ratio of radiated power to power supplied
Efficiency to antenna = $\frac{I^2 R_r}{I^2 (R_r + R_{loss})}$

$$G = \frac{4\pi A_e}{\lambda^2} \quad [20\%]$$

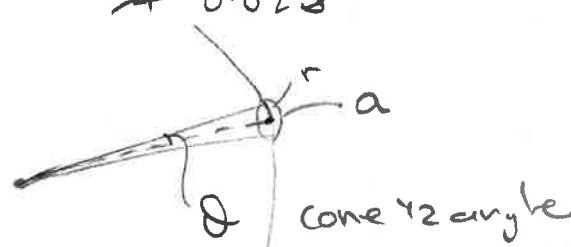
(b) $R = 507 \times 10^9$ m
 $f = 10.7 \times 10^9$ Hz , $\lambda = \frac{c}{f} = 0.028$ m
 $P_t = 750$ W
 $A_{et} = \frac{\pi r^2}{4}$ m² , $A_{er} = \frac{\pi r^2}{4}$

(i) $P_r = \frac{V_r^2}{50} = \frac{P_t \times G \times A_{er}}{4\pi R^2}$ where $G = \frac{A_{et} \cdot 4\pi}{\lambda^2}$

$$\therefore P_r = \frac{750 \cdot \frac{\pi r^2}{4} \cdot \frac{\pi r^2}{4} \cdot \frac{4\pi}{0.028^2}}{4\pi (507 \times 10^9)^2} = 5.44 \times 10^{-14} \text{ W}$$

$$\therefore V_r = \sqrt{(5.44 \times 10^{-14} \cdot 50)} = 1.65 \mu\text{V} \quad [15\%]$$

(ii) $G = \frac{4\pi \frac{\pi r^2}{4} \cdot \frac{\pi r^2}{4}}{0.028^2} = \frac{60.9 \times 10^3}{4\pi R^2} = \left(\frac{\pi r^2}{4\pi R^2} \right)^{-1}$



where $r = R \sin \theta$
 $= \left(\frac{\pi R^2 \sin^2 \theta}{4\pi R^2} \right)^{-1}$

$$\therefore \sin \theta = \left(\frac{60.9 \times 10^3}{4} \right)^{-1/2}$$

$$\therefore \theta = 0.46^\circ \quad [20\%]$$

1(c)



$$2.7 \text{ GHz} \Rightarrow \lambda = 0.111 \text{ m}$$

$$\therefore \lambda/2 \text{ dipole length} = 0.0556 \text{ m}$$

skin depth, $\delta_{\text{steel}} = \sqrt{\frac{2\rho}{\omega\mu_0}} = \sqrt{\frac{2 \times 72 \times 10^{-8}}{2\pi \times 2.7 \times 10^9 \times 4\pi \times 10^{-7}}} = 8.22 \mu\text{m}$

$$\rho_{\text{steel}} = 72 \times 10^{-8} \Omega\text{m}$$

$$\rho_{\text{Cu}} = 1.72 \times 10^{-8} \Omega\text{m}$$

$$\text{and for Cu, } \delta_{\text{Cu}} = 1.27 \mu\text{m}$$

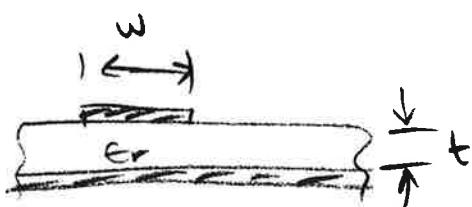
Resistance $\left\{ \begin{array}{l} \text{Steel : } \frac{\rho \times L}{\delta_{\text{steel}}} : 1.55 \Omega \\ \text{Cu : } \frac{\rho \times L}{\pi \delta \times d} : 0.124 \Omega \end{array} \right.$

$$d = 0.001 \text{ m}$$

$$R_r \text{ for } \lambda/2 \text{ dipole} \approx 75 \Omega$$

$$\therefore \eta_{\text{rad}} = \frac{R_r}{R_r + R_{\text{shunt}}} = \frac{0.980}{\delta_{\text{steel}} \text{ (Cu)}} \rightarrow 0.997 [20\%]$$

1(d)



capacitance / unit length = $C = \frac{(w+2t)\epsilon_r\epsilon_0}{t}$

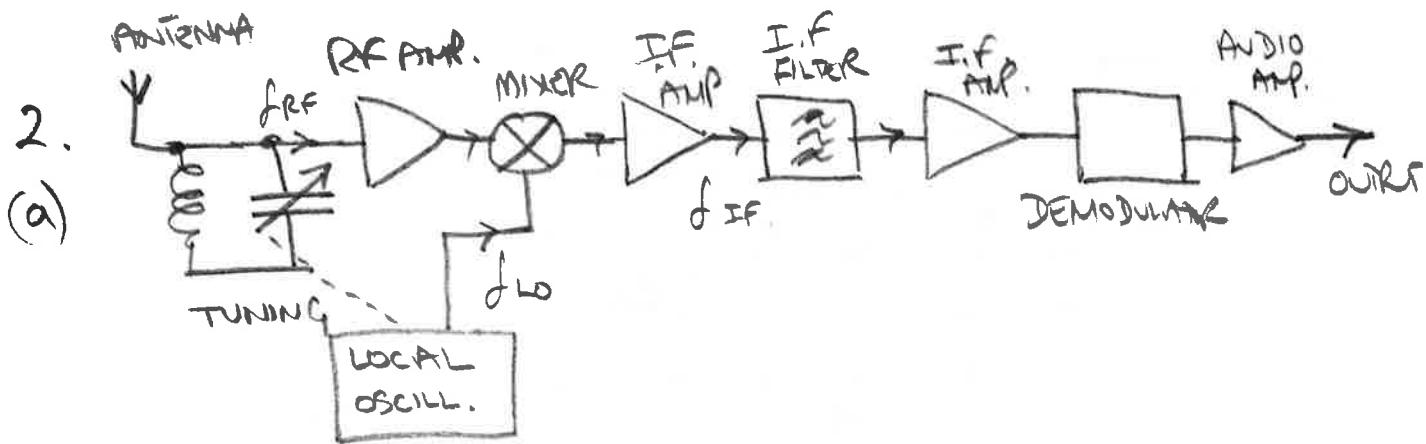
$$V = \frac{1}{\sqrt{\epsilon_0\epsilon_r\mu_0}} = 2.12 \times 10^8 \text{ m/s} = \frac{1}{\sqrt{Lc}}$$

$$\therefore \sqrt{Lc} = \frac{1}{\sqrt{Lc}} \text{ and } Z_0 = \frac{\sqrt{Lc}}{\sqrt{C}} = \frac{1}{\sqrt{C}} \quad \therefore Z_0 C = \frac{1}{\sqrt{C}}$$

$$\therefore \frac{50(\omega+2t)\epsilon_0\epsilon_r}{t} = \frac{1}{2.12 \times 10^8}$$

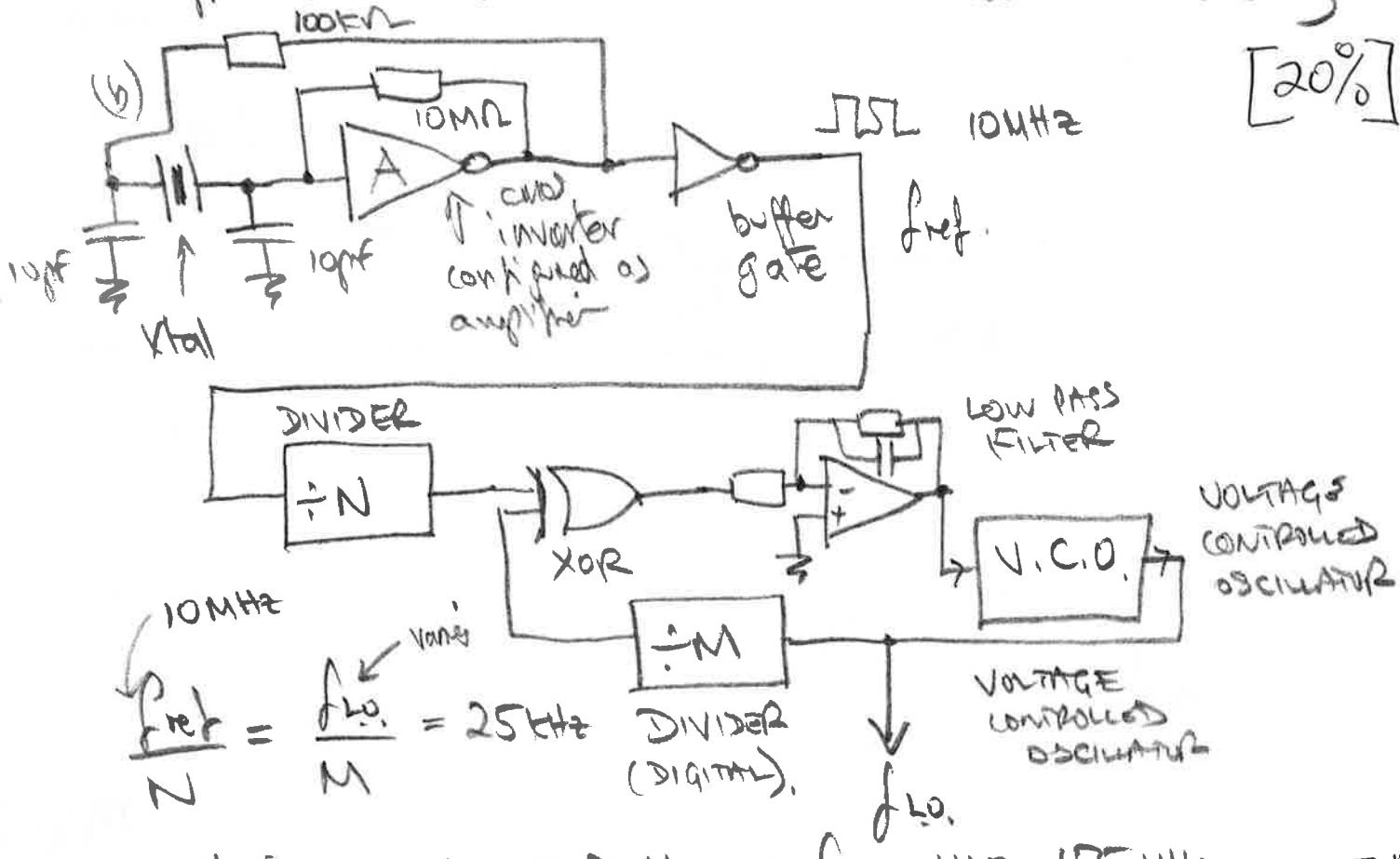
$t \uparrow 0.8 \times 10^{-3} \text{ m}$

$$\therefore \omega + 1.6 \times 10^3 = 4.26 \times 10^3 \quad \therefore \omega = 2.66 \times 10^3 \text{ [25%]}$$



The RF signal is amplified at input to a mixer, which multiplies it by the local oscillator signal. Sum & difference frequencies are produced by the mixer - usually the (lower) difference frequency is selected by the I.F. filter. This is amplified and demodulated to extract the audio information.
 $f_{IF} = (f_{LO} - f_{RF})$

To tune the radio, the local oscillator is varied and the 'image reject' resonant front end resonance is also varied to keep it a fixed (ideally) frequency difference from the local oscillator - this is known as 'tracking'.



$$f_{ref} = \frac{f_{LO}}{N} = 25\text{ kHz}$$

DIVIDER (DIGITAL).

LOW PASS FILTER

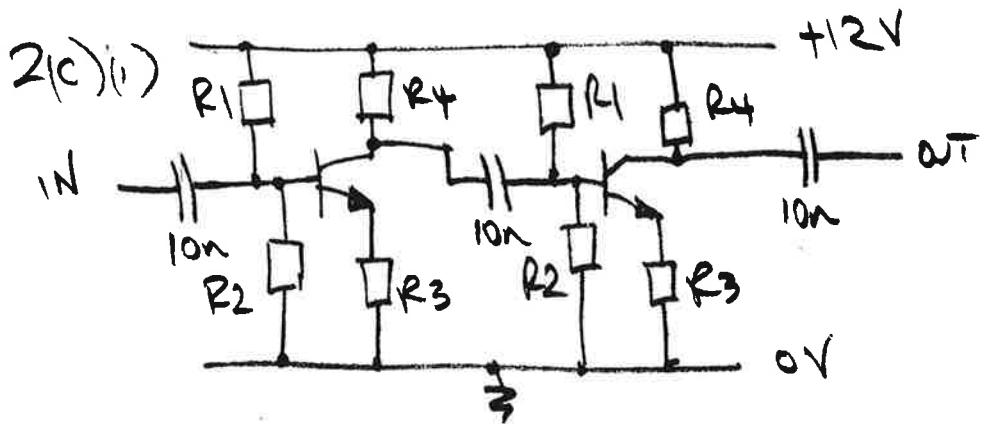
VOLTAGE CONTROLLED OSCILLATOR

VOLTAGE CONTROLLED OSCILLATOR

tuning range 120-135 MHz $\therefore f_{LO}$ 140-155 MHz

$$N = 400$$

[20%]



cascade 2 identical stages for 30 dB

$$R_L = 50\Omega, \text{ for } 15 \text{ dB gain/stage} = x 5.62 \text{ linear } x 2 \\ \text{for loading requirement} \\ = x 12$$

$$\therefore \underline{R_3 = 3.9 \Omega} \text{ say}$$

$$\therefore \text{Net Gain} = \frac{50}{3.9+0.2} = 12.7$$

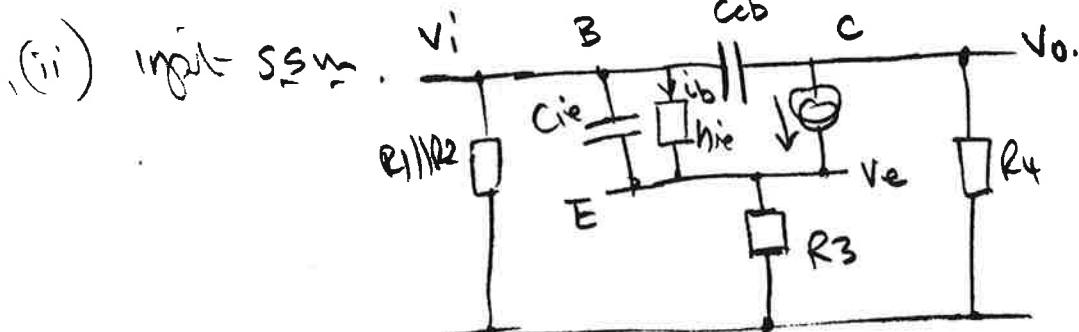
$$I_c = \frac{50}{1212} = 0.12A \quad \therefore r_e = \frac{0.025}{0.12} = 0.2\Omega$$

$$R_2 = \frac{100\Omega}{(2 \times R_1)} \quad (\because h_{ie} = 50\Omega)$$

$$V_e = 0.12 \times 3.9 = 0.47 V \quad \therefore 0.65 = 1.1 V \text{ for } V_{\text{bare}}. \\ + 10\% \text{ say for load.}$$

$$\therefore \left(\frac{R_2}{R_1 + R_2} \right) \times 12 = 1.2 \quad \therefore \underline{R_1 = 910 \Omega}$$

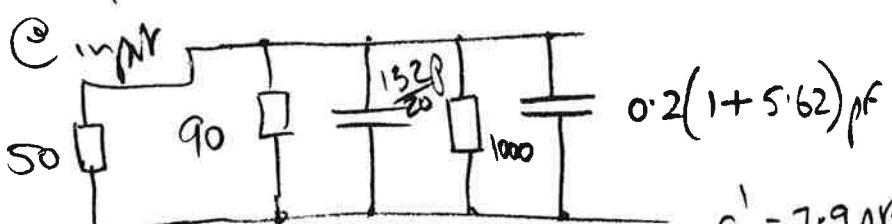
[35%]



$$6 \times 10^9 = \frac{1}{27 \text{ recie}}$$

$$\Rightarrow C_{le} = 132 \text{ } \mu\text{F}$$

$$V_e = V_i \frac{R_3}{R_3 + r_e} = 0.95$$



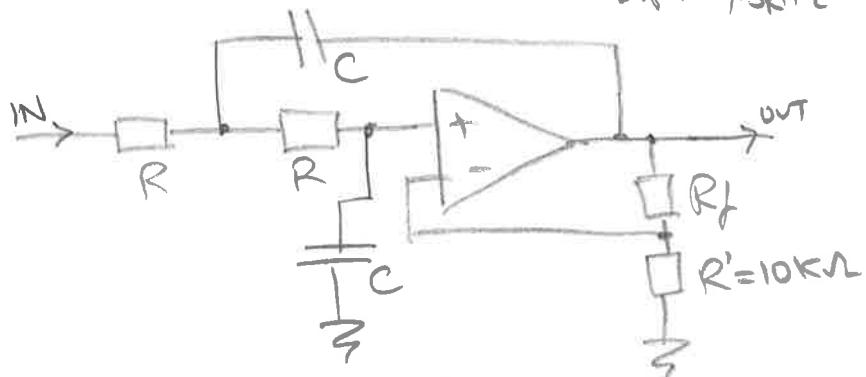
$$C_1 = 7.9 \rho F$$

$$k = 31 \text{ N}$$

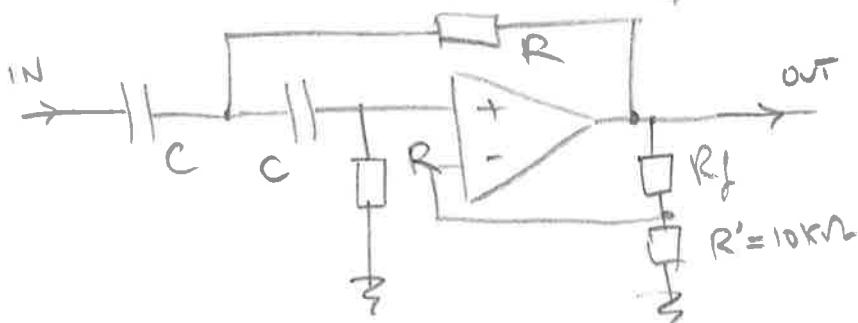
$$\therefore f^{-3dB} = \frac{1}{2\pi r'c'} = \underline{\underline{646 \text{ MHz}}}$$

B-E values
x20 is grad.
for impedance
 \checkmark [25%] O.K.

3(a) Bandpass 0.1-75kHz \therefore H.P. 0.1Hz
 L.P. 75kHz } cascaded.



Low Pass
 $\times 2$ stages
 (1 & 2)



High Pass
 $\times 2$ stages
 (3 & 4)

VAF Based filter for best transient response.

$$C = 100\text{nF}, \text{ for L.P. } f_{c0} = \frac{1}{2\pi f_n R C}$$

$$\frac{1.432}{1.606} \rightarrow \therefore R = 148 \Omega \quad (1)$$

$$148 \Omega \quad (2)$$

$$\text{for H.P. } 100 = \frac{f_n}{2\pi R C} \quad \therefore R = 22.8\text{k}\Omega \quad (3)$$

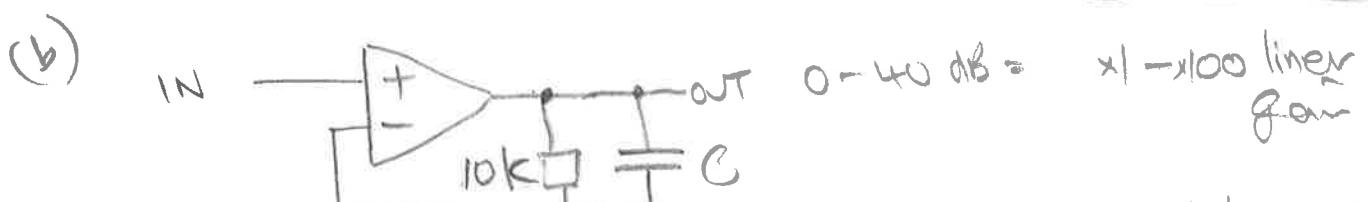
$$25.6\text{k}\Omega \quad (4)$$

$$G_i = R_f / R' + 1 \quad \therefore \varphi R_f = 10 \times 0.084 \text{k}\Omega = 840 \Omega$$

$$② = 10 \times 0.759 \text{k}\Omega = 7.6 \text{k}\Omega$$

$$③ = 10 \times 0.084 \text{k}\Omega = 840 \Omega \quad [35\%]$$

$$④ = 10 \times 0.759 \text{k}\Omega = 7.6 \text{k}\Omega$$

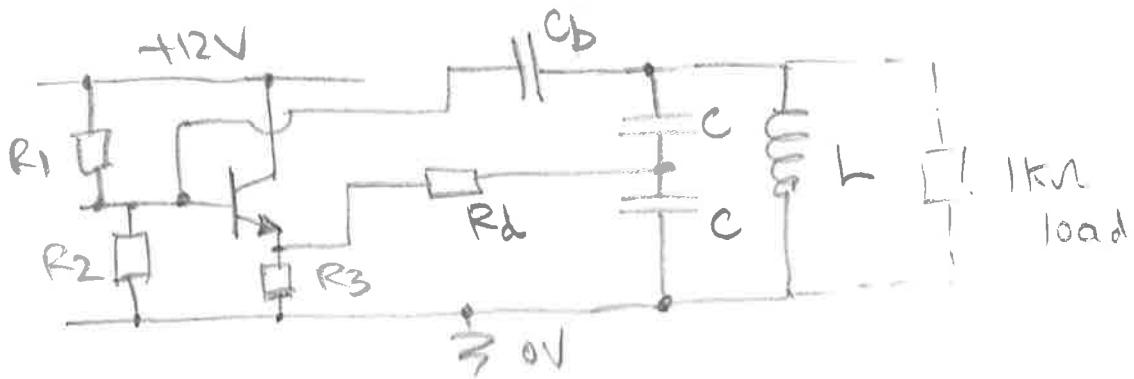


$V_{control}$ - op-amp gain bandwidth
 $>100\text{MHz}$

non-inverting enhancement. MOSFET $R_{ds(on)} < 10\Omega$

$$3(b) \text{ contd. } 10^6 = \frac{1}{2\pi f C} \therefore C = 16 \mu F \quad [25\%]$$

3(c) note V_{DS} of MOSFET $V_{DS(on)} > 2.5 \text{ V}$ for conduction
 \Rightarrow higher gain.



$$C_D = C = 10 \text{ nF}$$

$$\therefore \text{for } 2 \text{ MHz}, f = \frac{1}{2\pi \sqrt{LC/2}}$$

$$\therefore L = 1.27 \text{ }\mu\text{H}$$

$$\text{for parasitic losses } R' = \frac{WLQ}{\uparrow \text{ so say.}} \approx 800\Omega \parallel 1\text{k}\Omega \text{ load} \approx 450\Omega$$

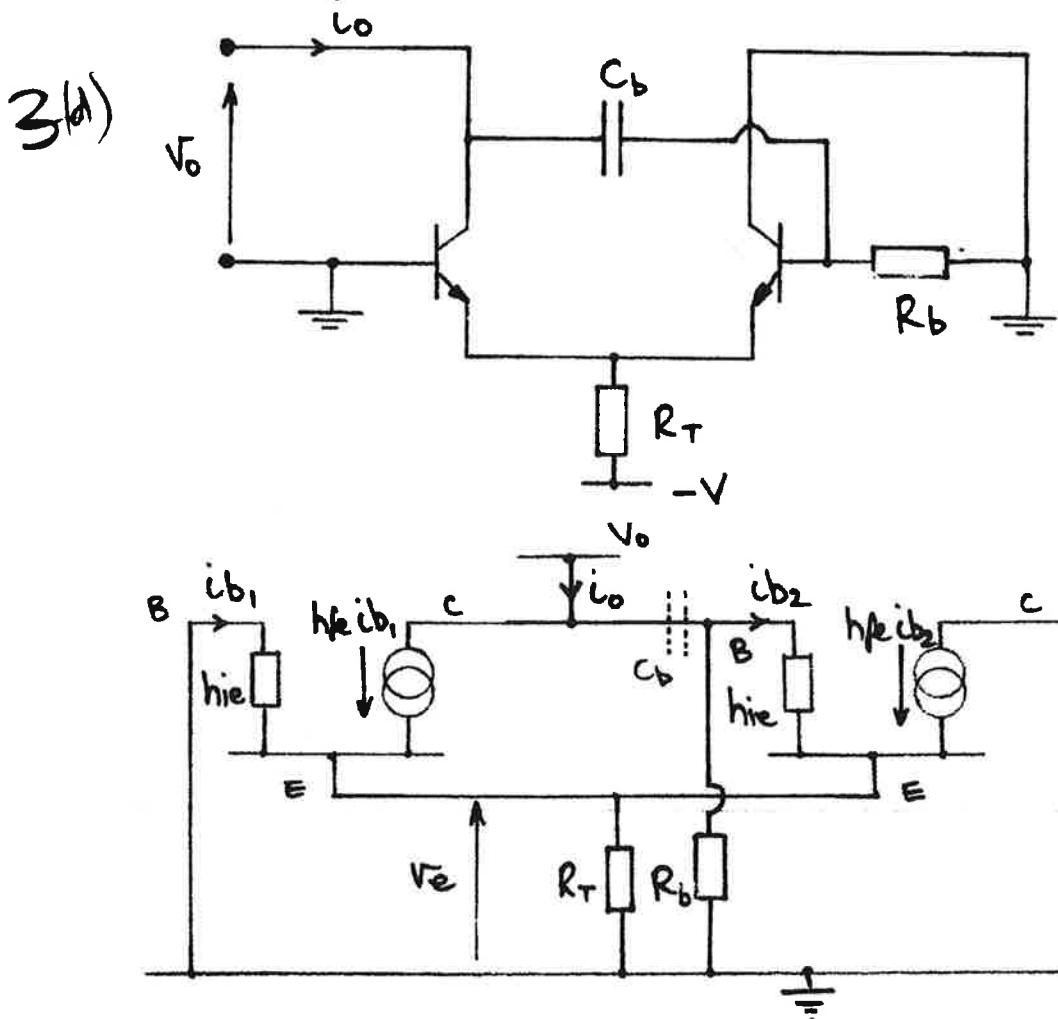
$$\therefore R_1 \text{ and } R_2 \approx 1\text{k}\Omega$$

$$R_3 \approx 450\Omega$$

$$R_d \approx 300\Omega \text{ for loop gain } > 1.$$

$$\therefore \text{to set } V_D @ 6V \text{ dc. (V}_2 \text{ supply)}, \text{ set } R_1 = R_2 \\ = 2\text{k}\Omega$$

[20%]



$$\textcircled{1} \quad i_{b1} = -\frac{V_e}{h_{ie}} , \quad \textcircled{2} \quad i_{b2} = \frac{V_o - V_e}{h_{ie}} , \quad \textcircled{3} \quad V_e \approx R_T h_{fe}(i_{b1} + i_{b2}) ,$$

$$\textcircled{4} \quad i_o = h_{fe} i_{b1} + i_{b2} + V_o / R_b \quad \text{Subst. } \textcircled{1} \text{ and } \textcircled{2} \text{ into } \textcircled{3} :-$$

$$V_e = -R_T h_{fe} \frac{V_e}{h_{ie}} + R_T h_{fe} \frac{V_o}{h_{ie}} - R_T h_{fe} \frac{V_e}{h_{ie}}$$

$$\therefore V_e \left(1 + \frac{2R_T h_{fe}}{h_{ie}} \right) = R_T \frac{h_{fe} V_o}{h_{ie}} \quad \therefore V_e \approx \frac{V_o}{2} \quad \textcircled{5}$$

Subst. $\textcircled{1}$ and $\textcircled{2}$ into $\textcircled{4}$ and subst. for V_e usifg $\textcircled{5}$

$$\therefore i_o = -\frac{h_{fe} V_o}{2h_{ie}} + \cancel{\frac{V_o}{2h_{ie}}} + \frac{V_o}{R_b}$$

$$\therefore i_o = V_o \left(\frac{1}{R_b} - \frac{h_{fe}}{2h_{ie}} \right) \quad \text{and as } \frac{h_{ie}}{h_{fe}} = r_e, [20\%]$$

$$Z_o = \frac{V_o}{i_o} = \left(\frac{1}{R_b} + \frac{1}{-2r_e} \right)^{-1} \Rightarrow Z_o = R_b \parallel -2r_e$$

4(a)(i)

$$(2.50 - 2.49) \times 10^{-9} = \frac{1}{2\pi\sqrt{LC}}$$

$$\therefore C = 2.53 \text{ nF}$$

[10%]

$$(ii) Q = \frac{\omega L}{R} = \frac{2\pi \cdot 10 \times 10^6 \cdot 100 \times 10^{-9}}{0.4} = 15.7$$

$$\therefore B/w = \frac{f_0}{Q} = \frac{10 \times 10^6}{15.7} = \underline{637 \text{ kHz}} \quad [10\%]$$

Q1 Antennas & microstrip

The first part on antenna terms was well answered and similarly so for the signal calculation, although some candidates confused the antenna areas or used both the gain and aperture for the same dish. The final part on microstrip design was well attempted by most candidates.

Q2 Superhet, Phase Locked Loop, RF amplifier

The Superhet schematic was known by all candidates and most knew correctly how it was tuned. The phase locked loop presented more of a challenge to some although there were some very good attempts. The final section on amplifier design required a 2 transistor circuit to achieve sufficient gain and bandwidth, which caught out a few people. The bandwidth calculation was nonetheless quite well attempted in general.

Q3 VCVS filter, variable gain amplifier, Colpitts oscillator

Another well answered question in general. Most candidates could design the VCVS filter correctly although a number of candidates did not select the correct type (Bessel). The variable gain amplifier and Colpitts oscillator circuits were also recalled correctly by most, however, the superfluous amplitude feedback components shown in the notes were often included as well.

Q4 Impedance matching, Smith chart

Most attempts correctly evaluated the simple LC resonant circuit values although the Q-factor and bandwidth estimate foxed some people. The Smith chart section was generally well attempted for the first part although the following sections presented more of a challenge and there were only a few correct attempts.

P. A. Robertson (Principal Assessor)